

| | Application No. | Applicant(s) |
|--|---|--|
| Notice of Allowability | 10/805,070 | JAIN ET AL. |
| | Examiner | Art Unit |
| | Thao P. Le | 2818 |
| The MAILING DATE of this communication appears on the cover sheet with the correspondence address All claims being allowable, PROSECUTION ON THE MERITS IS (OR REMAINS) CLOSED in this application. If not included herewith (or previously mailed), a Notice of Allowance (PTOL-85) or other appropriate communication will be mailed in due course. THIS NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT RIGHTS. This application is subject to withdrawal from issue at the initiative of the Office or upon petition by the applicant. See 37 CFR 1.313 and MPEP 1308. | | |
| 1. This communication is responsive to 3/22/04. | | |
| 2. The allowed claim(s) is/are <u>1-27</u> . | | |
| 3. X The drawings filed on 22 March 2004 are accepted by the Examiner. | | |
| 4. Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some* c) None of the: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this national stage application from the International Bureau (PCT Rule 17.2(a)). * Certified copies not received: | | |
| Applicant has THREE MONTHS FROM THE "MAILING DATE" of this communication to file a reply complying with the requirements noted below. Failure to timely comply will result in ABANDONMENT of this application. THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. | | |
| 5. A SUBSTITUTE OATH OR DECLARATION must be submitted. Note the attached EXAMINER'S AMENDMENT or NOTICE OF INFORMAL PATENT APPLICATION (PTO-152) which gives reason(s) why the oath or declaration is deficient. | | |
| 6. CORRECTED DRAWINGS (as "replacement sheets") must be submitted. (a) including changes required by the Notice of Draftsperson's Patent Drawing Review (PTO-948) attached 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examiner's Amendment / Comment or in the Office action of Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR 1.84(c)) should be written on the drawings in the front (not the back) of each sheet. Replacement sheet(s) should be labeled as such in the header according to 37 CFR 1.121(d). | | |
| 7. DEPOSIT OF and/or INFORMATION about the deposit of BIOLOGICAL MATERIAL must be submitted. Note the attached Examiner's comment regarding REQUIREMENT FOR THE DEPOSIT OF BIOLOGICAL MATERIAL. | | |
| Attachment(s) 1. ☑ Notice of References Cited (PTO-892) 2. ☐ Notice of Draftperson's Patent Drawing Review (PTO-948) 3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date | 6. ☐ Interview S Paper No 8), 7. ☐ Examiner | nformal Patent Application (PTO-152) Summary (PTO-413), ./Mail Date s Amendment/Comment s Statement of Reasons for Allowance |
| 4. Examiner's Comment Regarding Requirement for Deposit of Biological Material . | 9. ☐ Other | |

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DETAILED ACTION

EXAMINER'S AMENDMENT

Amend the specification as following:

Page 1, line 2, change " (now allowed)" to --- now U.S. Patent No. 6, 797,412 ---

Page 1, line 5, change "nanophorphor" to --- nanophosphor---

Claims 1-27 are pending in this application.

Reason for allowance

Claims 1-27 are allowed. The following is an examiner's statement of reason for allowance: None of the references of record teaches or suggests the claimed limitations having an EL device comprising a second p-type semiconductor layer grown epitaxially, the second layer having an energy gap larger than both the first Si layer and a pseudomorphic cladding of the quantum dot nanocrystal layer (CNC), a layer comprising pseudomorphic cladded quantum dots nanocrystals (CNC) with both cladding and core semiconductors having narrower energy gap than the second p-type layer for electroluminescence, and an n-type semiconductor layer thinner than the substrate, wider energy gap than the cladding and core layers of cladded quantum dot nanocrystalls grown on the CNC layer and other limitations cited in independent claim 1.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably

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accompany the issue fee. Such submissions should be clearly labeled "Comments on

Statement of Reasons for Allowance".

Conclusion

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thao P. Le whose telephone number is 571-272-1785. The examiner can normally be reached on M-T (7-6).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on 571-272-1787. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thao P. Le

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